

Features and Benefits

- Epitaxial Planar Die Construction
- Two Pre-Biased Transistors and Two Switching Diodes, Internally Connected in One Package
- Ideally Suited for Automated Assembly Processes
- **Lead Free By Design/RoHS Compliant (Note 1)**
- **"Green" Device (Note 2)**
- **Qualified to AEC-Q101 standards for High Reliability**

R1 = R3 = 2.2kΩ (nominal)

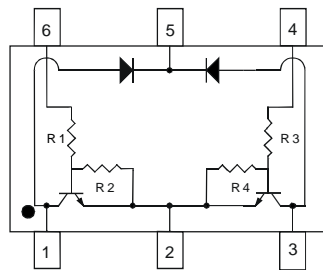
R2 = R4 = 47kΩ (nominal)

Mechanical Data

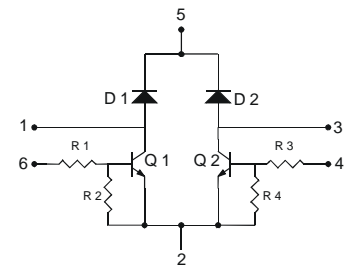
- Case: SOT-363
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish - Matte Tin annealed over Alloy 42 leadframe. Solderable per MIL-STD-202, Method 208
- Weight: 0.0062 grams (approximate)



Top View



Top View



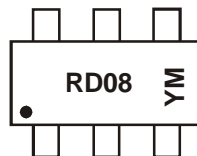
Device Circuit

Ordering Information (Note 3)

Device	Packaging	Shipping
DRDNB21D-7	SOT-363	3000/Tape & Reel

- Notes:
1. No purposefully added lead.
 2. Diodes Inc.'s "Green" Policy can be found on our website at <http://www.diodes.com>
 3. For packaging details, visit our website at <http://www.diodes.com>.

Marking Information



RD08 = Product Type Marking Code
 YM = Date Code Marking
 Y = Year (e.g. T = 2006)
 M = Month (e.g. 1 = January)

Date Code Key

Year	2005	2006	2007	2008	2009	2010	2011	2012	2013	2014	2015	2016
Code	S	T	U	V	W	X	Y	Z	A	B	C	D
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Maximum Ratings, Total Device @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 4)	P_D	200	mW
Thermal Resistance, Junction to Ambient Air (Note 4)	$R_{\theta JA}$	625	$^\circ\text{C/W}$
Operating and Storage Junction Temperature Range	T_J, T_{STG}	-55 to +150	$^\circ\text{C}$

Maximum Ratings, Pre-Biased NPN Transistor @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CC}	50	V
Base-Emitter Voltage	V_{in}	-5 to +12	V
Output Current	I_O	100	mA
Peak Collector Current	I_{CM}	100	mA

Maximum Ratings, Switching Diode @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Non-Repetitive Peak Reverse Voltage	V_{RM}	100	V
Peak Repetitive Reverse Voltage	V_{RRM}	75	V
Working Peak Reverse Voltage	V_{RWM}		
DC Blocking Voltage	V_R		
RMS Reverse Voltage	$V_{R(RMS)}$	53	V
Forward Continuous Current (Note 4)	I_{FM}	500	mA
Average Rectified Output Current (Note 4)	I_O	250	mA
Non-Repetitive Peak Forward Surge Current @ $t = 1.0\mu\text{s}$	I_{FSM}	4.0	A
@ $t = 1.0\text{s}$		1.0	

Electrical Characteristics, Pre-Biased NPN Transistor @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Input Voltage	$V_{I(off)}$	0.5	—	—	V	$V_{CC} = 5\text{V}, I_O = 100\mu\text{A}$
	$V_{I(on)}$	—	—	1.1	V	$V_O = 0.3\text{V}, I_O = 5\text{mA}$
Output Voltage	$V_{O(on)}$	—	—	0.3	V	$I_O/I_I = 50\text{mA}/0.25\text{mA}$
Input Current	I_I	—	—	3.6	mA	$V_I = 5\text{V}$
Output Current	$I_{O(off)}$	—	—	0.5	μA	$V_{CC} = 50\text{V}, V_I = 0\text{V}$
DC Current Gain	G_I	80	—	—	—	$V_O = 5\text{V}, I_O = 10\text{mA}$
Input Resistor Tolerance	$\Delta R1$	-30	—	+30	%	-
Resistance Ratio Tolerance	$\Delta R2/R1$	-20	—	+20	%	-
Gain-Bandwidth Product*	f_T	—	250	—	MHz	$V_{CE} = 10\text{V}, I_E = 5\text{mA}, f = 100\text{MHz}$

* Transistor - For Reference Only

Electrical Characteristics, Switching Diode @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 5)	$V_{(BR)R}$	75	—	V	$I_R = 10\mu\text{A}$
Forward Voltage	V_F	0.62	0.72	V	$I_F = 5.0\text{mA}$
		—	0.855		$I_F = 10\text{mA}$
		—	1.0		$I_F = 100\text{mA}$
		—	1.25		$I_F = 150\text{mA}$
Reverse Current (Note 5)	I_R	—	2.5	μA	$V_R = 75\text{V}$
		—	50	μA	$V_R = 75\text{V}, T_J = 150^\circ\text{C}$
		—	30	μA	$V_R = 25\text{V}, T_J = 150^\circ\text{C}$
		—	25	nA	$V_R = 20\text{V}$
Total Capacitance	C_T	—	4.0	pF	$V_R = 0, f = 1.0\text{MHz}$
Reverse Recovery Time	t_{rr}	—	4.0	ns	$I_F = I_R = 10\text{mA}, I_{rr} = 0.1 \times I_R, R_L = 100\Omega$

Notes: 4. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com>
5. Short duration pulse test used to minimize self-heating effect.

Device Characteristics

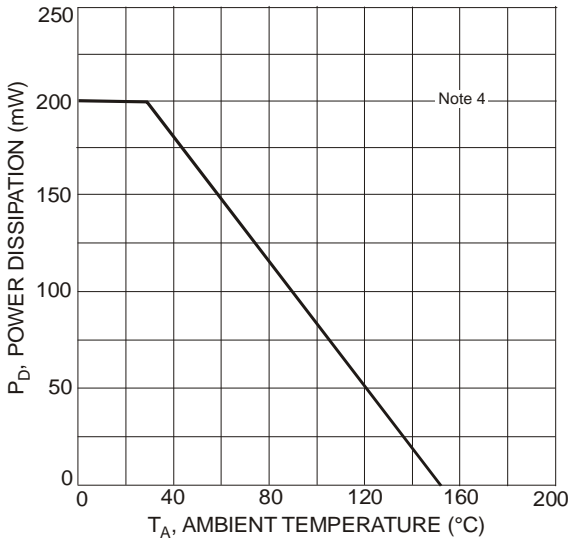


Fig. 1 Power Derating Curve (Total Device)

Pre-Biased NPN Transistor Elements

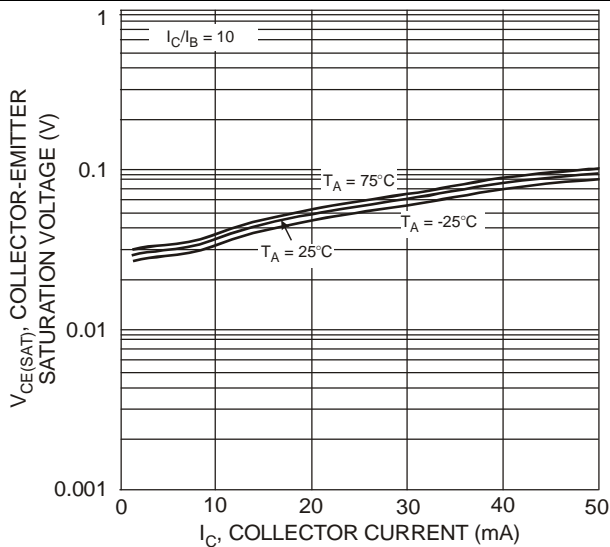


Fig. 2 Typical $V_{CE(SAT)}$ vs. I_C

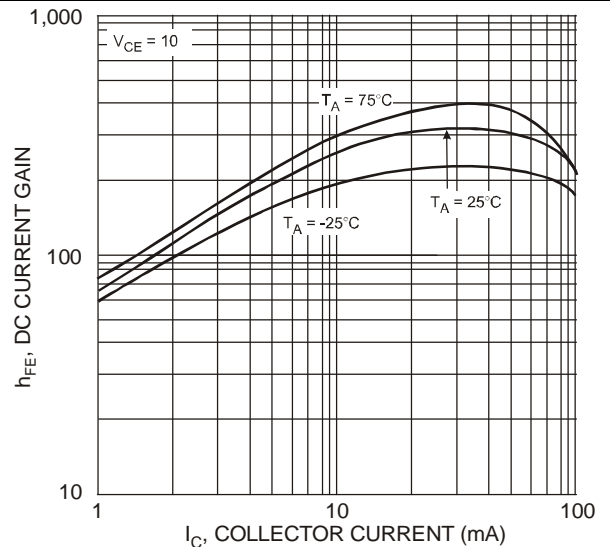


Fig. 3 Typical DC Current Gain

Pre-Biased NPN Transistor Elements - continued

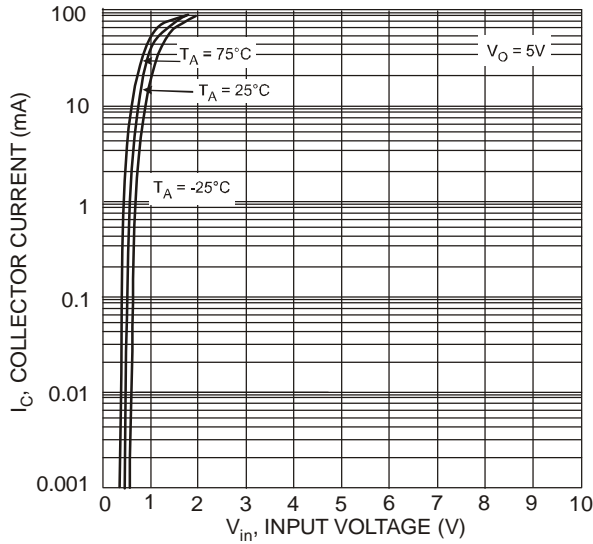


Fig. 4 Typical Collector Current vs. Input Voltage

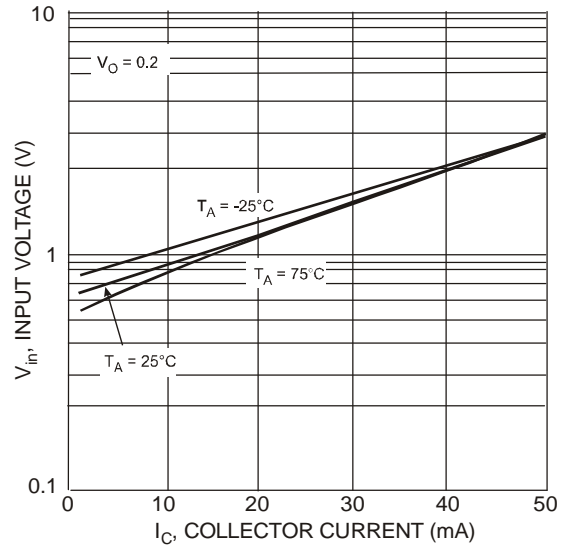


Fig. 5 Typical Input Voltage vs. Collector Current

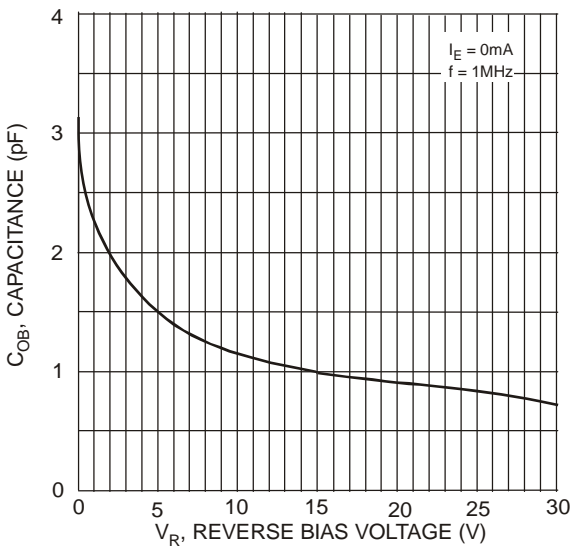


Fig. 6 Typical Output Capacitance

Switching Diode Elements

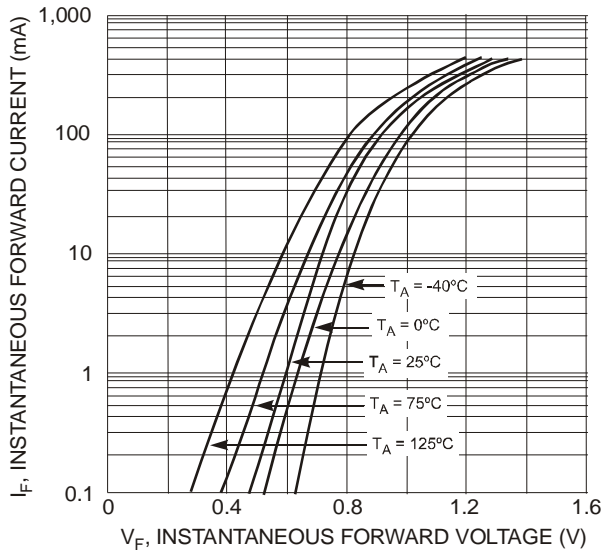


Fig. 7 Typical Forward Characteristics

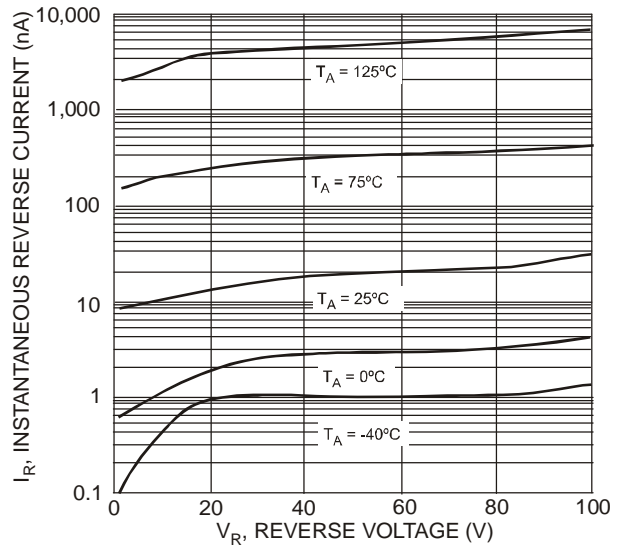


Fig. 8 Typical Reverse Characteristics

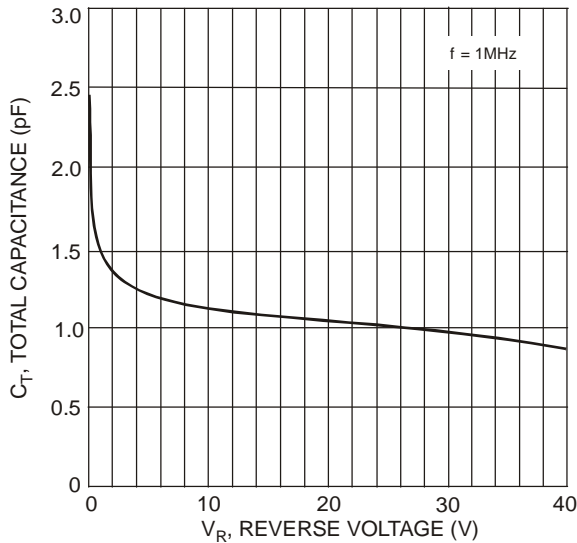
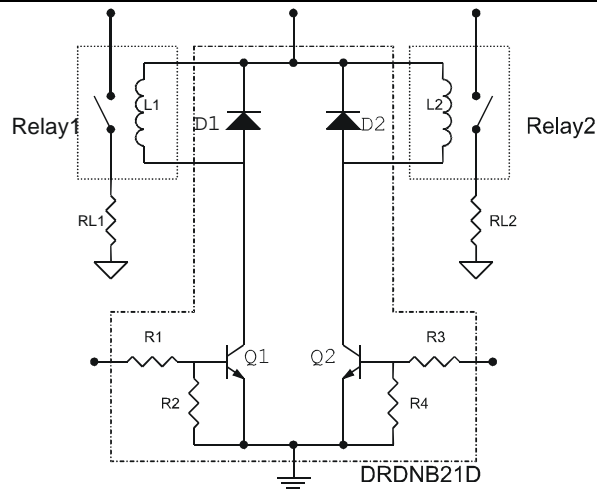


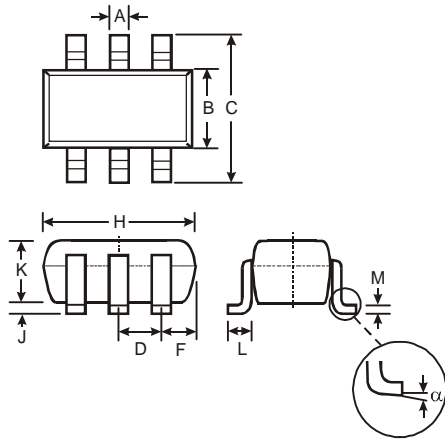
Fig. 9 Typical Capacitance vs. Reverse Voltage

Typical Application Circuit



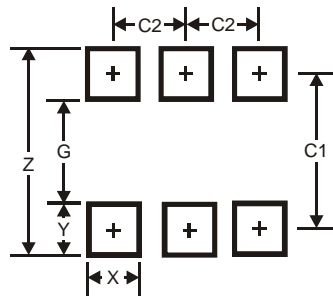
Typical Application Circuit DRDNB21D with two independent relays.

Package Outline Dimensions



SOT-363		
Dim	Min	Max
A	0.10	0.30
B	1.15	1.35
C	2.00	2.20
D	0.65 Typ	
F	0.40	0.45
H	1.80	2.20
J	0	0.10
K	0.90	1.00
L	0.25	0.40
M	0.10	0.22
α	0°	8°
All Dimensions in mm		

Suggested Pad Layout



Dimensions	Value (in mm)
Z	2.5
G	1.3
X	0.42
Y	0.6
C1	1.9
C2	0.65

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